

DESCRIPTION

The ES2ABF~ES2JBF is available in SMBF package

ORDERING INFORMATION

Package Type	Part Number				
	ES2ABF				
SMBF	ES2BBF				
	ES2CBF				
	ES2DBF				
	ES2EBF				
	ES2GBF				
	ES2JBF				
Note	SPQ: 5,000pcs/Reel				
AiT provides all RoHS Compliant Products					

FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Superfast reverse recovery time
- Available in SMBF package

MECHANICAL DATA

Case: SMBF

Terminals: Solderable per MIL-STD-750,

Method 2026

Approx. Weight: 57mg/ 0.002oz

PIN DESCRIPTION



ABSOLUTE MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

Parameter	Symbol	ES2ABF	ES2BBF	ES2CBF	ES2DBF	ES2EBF	ES2GBF	ES2JBF	Unit
Maximum Repetitive Peak I	V _{RRM}	50	100	150	200	300	400	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	420	V
Maximum DC Blocking Volt	V _{DC}	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current at T _L =100°C		I _{F(AV)}	2						Α
Peak Forward Surge Current 8.3ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)		I _{FSM}	30						А
Maximum Forward Voltage at 2A		VF	1 1.25 1.65				1.65	V	
Maximum DC Reverse Current at Rated DC Blocking Voltage	T _A =25°C T _A =125°C	I _R	5 100					uA	
Typical Junction Capacitance at V _R =4V, f=1MHz		Сл	45						pF
Maximum Reverse Recovery Time at I _F =0.5A, I _R =1A, I _{rr} =0.25A		t _{rr}	35						ns
Typical Thermal Resistance	R _{θJA}	65							°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 ~+150						°C

NOTE1: P.C.B. mounted with 0.5 X 0.5" (12.7 X 12.7 mm) copper pad areas.

TYPICAL CHARACTERISTICS

Figure. 1 Reverse Recovery Time Characteristic And Test Circuit Diagram

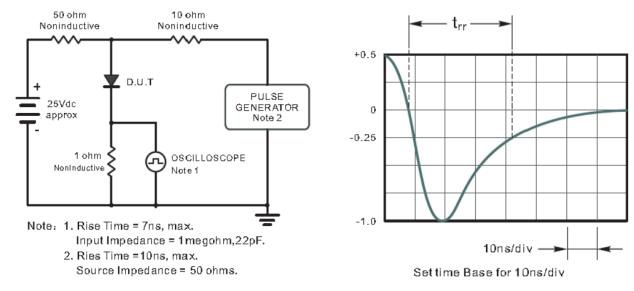
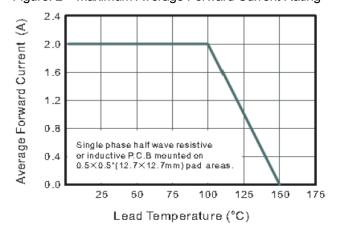


Figure. 2 Maximum Average Forward Current Rating



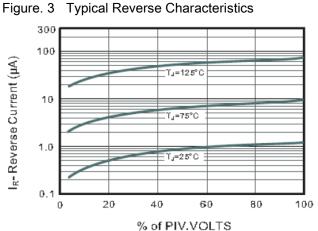
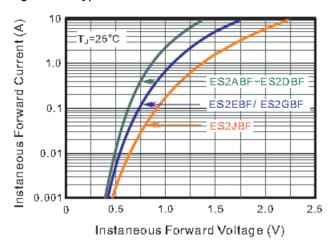


Figure. 4 Typical Forward Characteristics



60 Junction Capacitance (pF) 50 40 30 TJ=25°C

10

Reverse Voltage (V)

100

Figure. 5 Typical Junction Capacitance

f = 1.0MHz

 $V_{sig} = 50 \text{mV}_{p-p}$

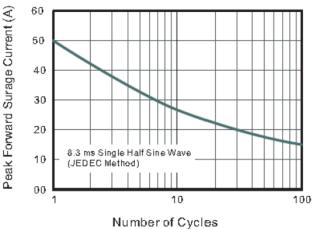
70

20

10

0.1

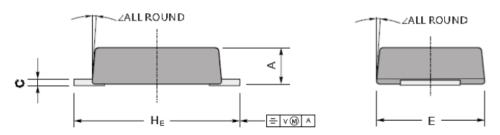
Figure. 6 Maximum Non-Repetitive Peak

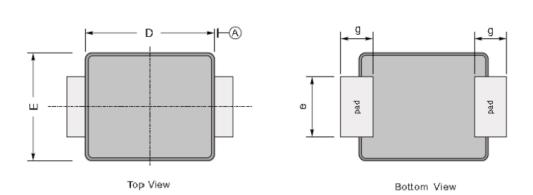


PACKAGE INFORMATION

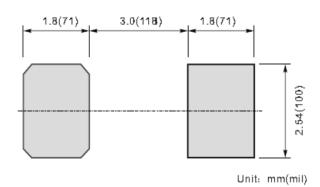
Dimension in SMBF (Unit: mm)

Plastic surface mounted package; 2 leads





The recommended mounting pad size



UNIT		Α	С	D	Е	HE	е	g	4
	Max	1.3	0.26	4.4	3.7	5.5	2.2	4.0	
mm	Min	1.1	0.18	4.2	3.5	5.1	1.9	1.0	O°
11	Max	51	10	173	146	216	86	40	9°
mil	Min	43	7	165	138	200	75	40	



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